

# FLINT

## High-Repetition-Rate Lasers

### FEATURES

- Repetition rate from 10 to 100 MHz
- Down to 50 fs pulse duration
- High-power models, up to 20 W
- High-energy energy models, up to 0.6  $\mu\text{J}$
- Industrial-grade design for high output stability
- CEP stabilization or repetition rate locking

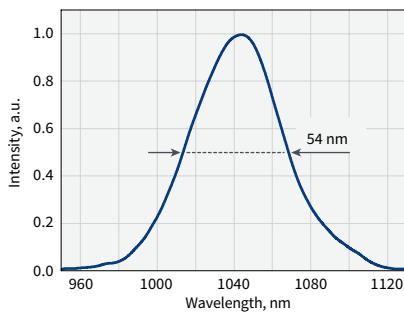


FLINT-FL1

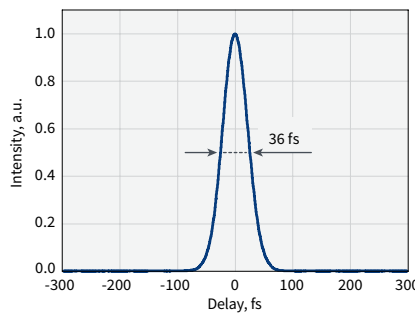
FLINT is a series of Yb-based femtosecond oscillators providing state-of-the-art output parameters. Backed by the proven industrial-grade design that is the core of the PHAROS and CARBIDE laser series, FLINT oscillators ensure excellent performance and stability over a long time.

The latest FLINT-FL2 oscillators offer output power of up to 20 W, pulse energy of up to 0.6  $\mu\text{J}$ , and pulse duration of down to 50 fs at the repetition rate of 11, 20, 40, or 76 MHz. Also, the second harmonic is available with an automated

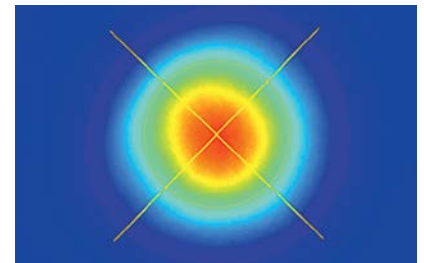
and fully integrated harmonic generator, while the third and fourth harmonic is obtainable with an external harmonic generator. The FLINT-FL1 oscillators support carrier-envelope phase (CEP) stabilization or repetition rate locking (RRL) to an external source with the repetition rate selection from 60 to 100 MHz. FLINT models come in standard and short-pulse (SP) configurations to fit the needs of most industrial and scientific applications.



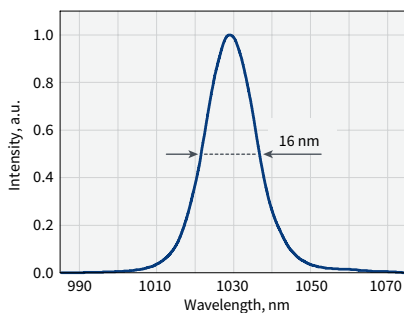
Typical spectrum of FLINT-FL2-SP



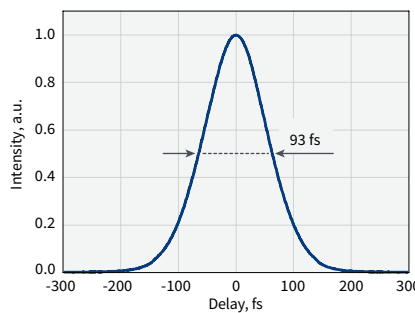
Typical pulse duration of FLINT-FL2-SP



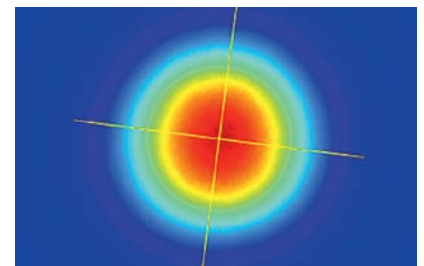
Typical beam profile of FLINT-FL2-SP



Typical spectrum of FLINT-FL1



Typical pulse duration of FLINT-FL1



Typical beam profile of FLINT-FL1

## SPECIFICATIONS

Model	FL1			FL2-SP				FL2			
Key feature	RRL or CEP	Compact footprint		Short pulse				High power and high energy			
Pulse duration <sup>1)</sup>	< 100 fs		< 120 fs	< 50 fs				< 120 fs		< 170 fs	
Repetition rate	60 – 100 MHz <sup>2)</sup>			11 MHz	20 MHz	40 MHz	76 MHz	11 MHz	20 MHz	40 MHz	76 MHz
Maximum output power	1 W	2 W	8 W	5 W				7 W		20 W	
Maximum pulse energy	13 nJ <sup>3)</sup>	26 nJ <sup>3)</sup>	105 nJ <sup>3)</sup>	440 nJ	250 nJ	125 nJ	65 nJ	0.6 μJ	0.35 μJ	0.5 μJ	0.26 μJ
Center wavelength	1035 ± 10 nm		1030 ± 3 nm	1035 ± 10 nm				1030 ± 10 nm		1026 ± 2 nm	
Polarization	Linear, horizontal										
Beam quality, M <sup>2</sup>	< 1.2			< 1.3				< 1.2			
Beam pointing stability	< 10 μrad/°C										
Pulse-to-pulse energy stability, 24 h <sup>4)</sup>	< 0.5%										
Long-term power stability, 100 h <sup>4)</sup>	< 0.5%										
Integrated 2H generator <sup>5)</sup>	n/a						Optional; see page 21				
External 2H, 3H, or 4H generator <sup>5)</sup>	Optional; see page 25										
Integrated attenuator	n/a			Included							

### PHYSICAL DIMENSIONS

Laser head (L × W × H)	430 × 197 × 114 mm	542 × 322 × 146 mm
Power supply and chiller rack (L × W × H)	642 × 553 × 540 mm	642 × 553 × 673 mm
Chiller	Different options available. Contact sales@lightcon.com	

### ENVIRONMENTAL AND UTILITY REQUIREMENTS

Operating temperature	15–30 °C (air conditioning recommended)	
Relative humidity	< 80% (non-condensing)	
Electrical requirements	100 V AC, 7 A – 240 V AC, 3 A; 50 – 60 Hz	100 V AC, 12 A – 240 V AC, 5 A; 50 – 60 Hz
Rated power	200 W	
Power consumption	Laser: 100 W; chiller: 200 W	Laser: 150 W; chiller: 800 W

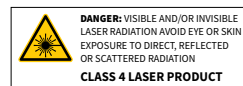
<sup>1)</sup> Models with shorter pulse duration available upon request.

<sup>2)</sup> Standard repetition rate is 76 MHz; custom repetition rate can be selected from the given range.

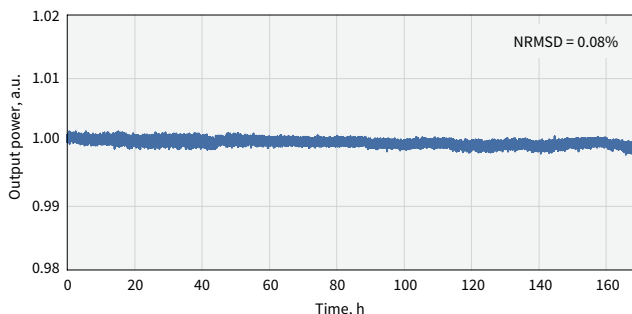
<sup>3)</sup> Depends on repetition rate. Values are given for 76 MHz.

<sup>4)</sup> With enabled power-lock, under stable. Expressed as NRMSD (normalized root mean squared deviation).

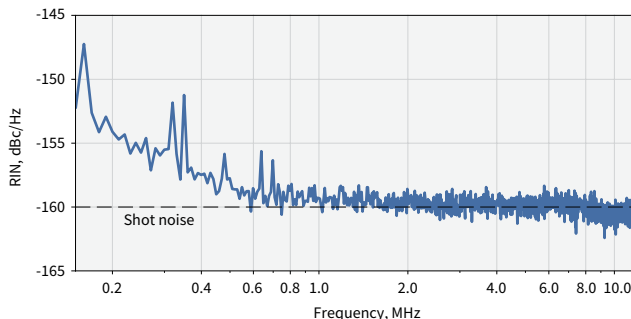
<sup>5)</sup> For external 2H, or even 3H and 4H generation, refer to HIRO for FLINT.



## STABILITY



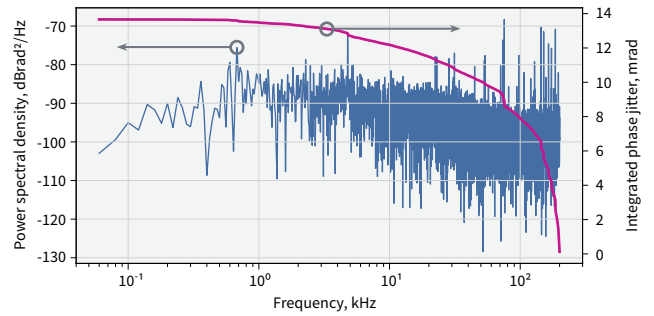
FLINT-FL2 (20W) output power stability under harsh environmental conditions over 7 days



Relative intensity noise (RIN) of FLINT oscillator, shot-noise limited at -160 dBc/Hz above 1 MHz

## CEP STABILIZATION

FLINT oscillators can be equipped with feedback electronics for carrier-envelope phase (CEP) stabilization of the output pulses. The carrier-envelope offset (CEO) of the oscillator is actively locked to 1/4<sup>th</sup> of the repetition rate with a <100 mrad standard deviation.

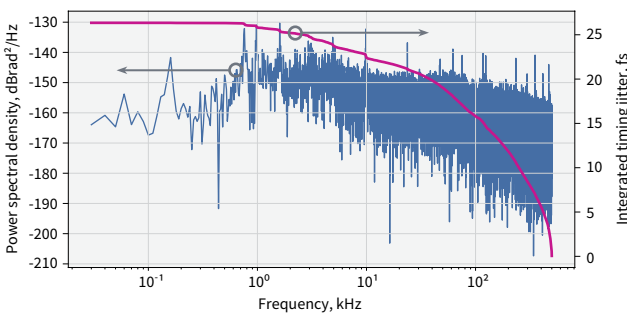


Phase noise data of CEP locked FLINT oscillator

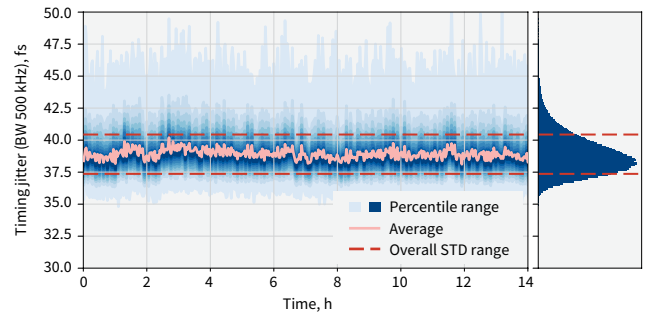
## REPETITION RATE LOCKING

FLINT oscillators are customizable for repetition rate locking applications. Coupled with the necessary feedback electronics, the repetition rate can be synchronized to an external RF source using the two piezo stages installed inside the cavity.

The repetition rate locking system can assure an integrated timing jitter of less than 200 fs for RF reference frequencies larger than 500 MHz. Continuous phase shifting is available on request.

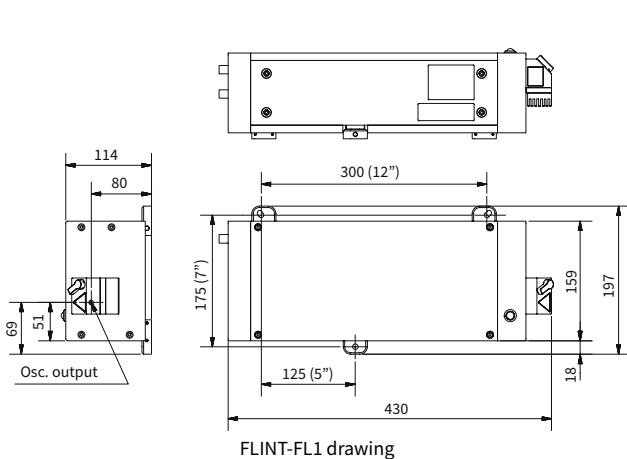


Phase noise data of FLINT oscillator locked to a 2.8 GHz RF source

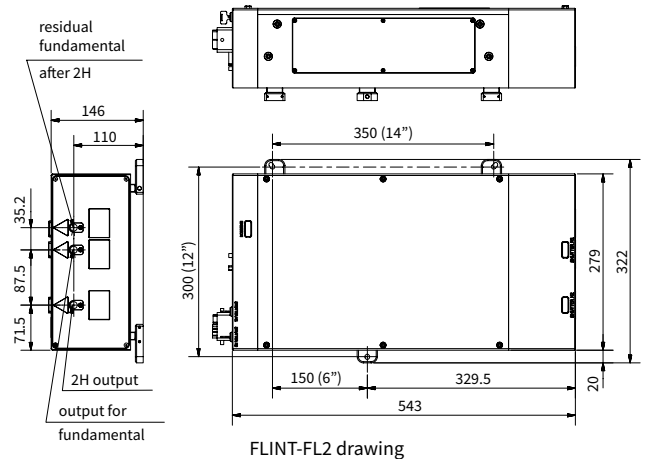


Timing jitter stability over 14 h; FLINT oscillator locked to a 2.8 GHz RF source

## DRAWINGS



FLINT-FL1 drawing



FLINT-FL2 drawing